## Lecture 22 - Multistage Amplifiers (II)

# DC Voltage and Current Sources

May 3, 2001

#### Contents:

- 1. DC voltage sources
- 2. DC current sources and sinks

## Reading assignment:

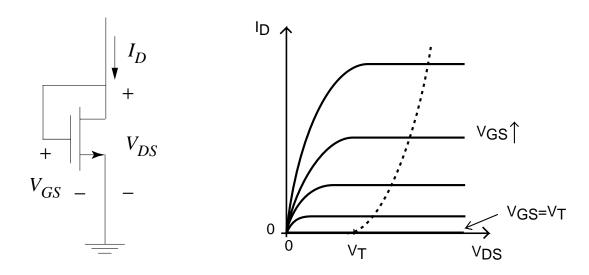
Howe and Sodini, Ch. 9, §§9.4

## Key questions

- How does one synthesize voltage and current sources?
- How can this be done in an economic way?

## 1. DC voltage sources

- ☐ Features of voltage source:
  - A well controlled voltage
  - voltage does not depend on current drawn from source (low internal resistance).
- □ Consider MOSFET in "diode configuration":



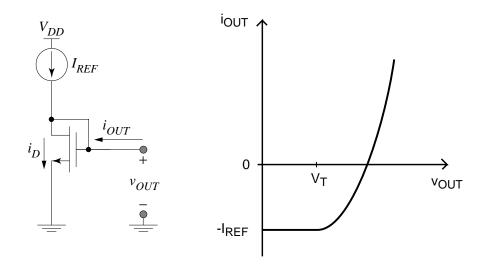
I-V characteristics:

$$I_D = \frac{W}{2L}\mu C_{ox}(V_{GS} - V_T)^2 = \frac{W}{2L}\mu C_{ox}(V_{DS} - V_T)^2$$

Beyond threshold, MOSFET looks like "diode" with quadratic I-V characteristics.

 $\square$  How does one synthesize a voltage source with this?

Assume a current source is available.



 $V_{GS} = V_{DS}$  takes value needed to sink current:

$$I_D = I_{REF} + i_{OUT} = \frac{W}{2L} \mu C_{ox} (v_{OUT} - V_T)^2$$

Then:

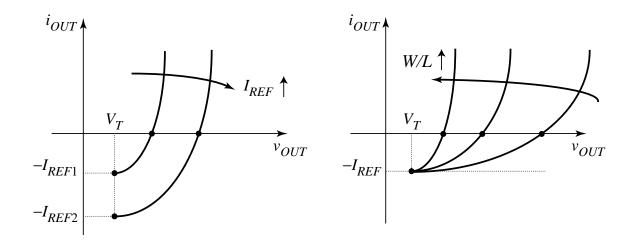
$$i_{OUT} = \frac{W}{2L} \mu C_{ox} (v_{OUT} - V_T)^2 - I_{REF}$$

Solving for  $v_{OUT}$ :

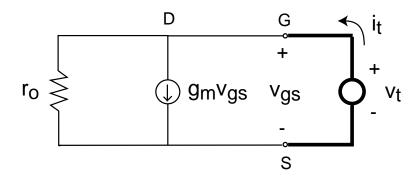
$$v_{OUT} = V_T + \sqrt{\frac{I_{REF} + i_{OUT}}{\frac{W}{2L}\mu C_{ox}}}$$

 $v_{OUT}$  is function of  $I_{REF}$  and W/L of MOSFET:

- $I_{REF} \uparrow \Rightarrow v_{OUT} \uparrow$
- $W/L \uparrow \Rightarrow v_{OUT} \downarrow$



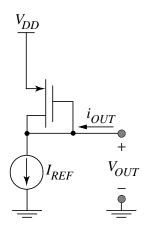
□ Small-signal view of voltage source:



$$R_{out} = \frac{1}{g_m} / / r_o \simeq \frac{1}{g_m}$$

 $R_{out}$  is small (good!).

## $\hfill\Box$ PMOS voltage source:



Same operation and characteristics as NMOS voltage source.

PMOS needs to be bigger to attain same  $R_{out}$ .

#### 2. DC current sources and sinks

- □ Features of current source:
  - A well controlled current,
  - supplied current does not depend on voltage across (high internal resistance)
- □ Connect voltage source to another MOSFET:

$$I_{OUT} \simeq \frac{1}{2} \left(\frac{W}{L}\right)_2 \mu C_{ox} (V_{REF} - V_T)^2$$

$$I_{REF} \simeq \frac{1}{2} \left(\frac{W}{L}\right)_1 \mu C_{ox} (V_{REF} - V_T)^2$$

$$I_{REF} \simeq \frac{1}{2} \left(\frac{W}{L}\right)_1 \mu C_{ox} (V_{REF} - V_T)^2$$

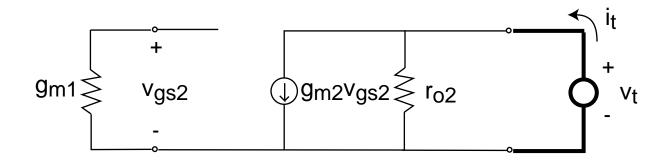
Then:

$$I_{OUT} = I_{REF} \frac{\left(\frac{W}{L}\right)_2}{\left(\frac{W}{L}\right)_1}$$

 $I_{OUT}$  scales with  $I_{REF}$  by W/L ratios of two MOSFETs (current mirror circuit).

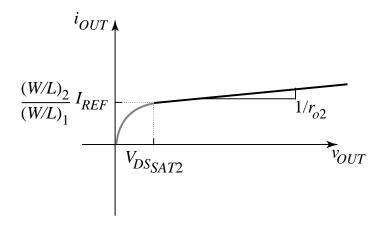
Well "matched" transistors important.

## • Small-signal view of current source:



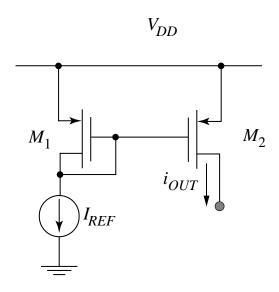
$$R_{out} = r_{o2}$$

## I-V characteristics of NMOS current source:



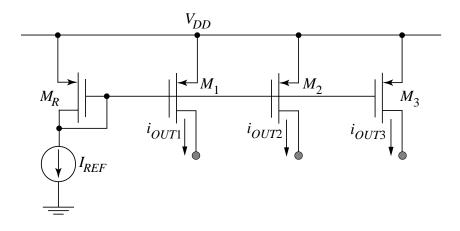
- □ PMOS current source
- ullet NMOS current source sinks current to ground.
- PMOS current source *sources* current from positive supply.

## PMOS current mirror:



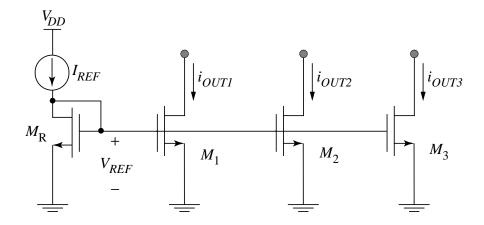
## □ Multiple current sources

Since there is no DC gate current in MOSFET, can tie up multiple current mirrors to single current source:



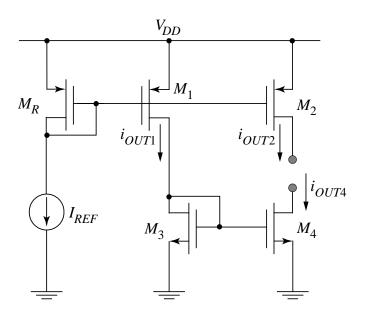
$$I_{OUTn} = I_{REF} \frac{\left(\frac{W}{L}\right)_n}{\left(\frac{W}{L}\right)_R}$$

Similar idea with NMOS current sinks:



## □ Multiple current sources and sinks

Often, in a given circuit, we need current sources and sinks. Can build them all out of a single current source:



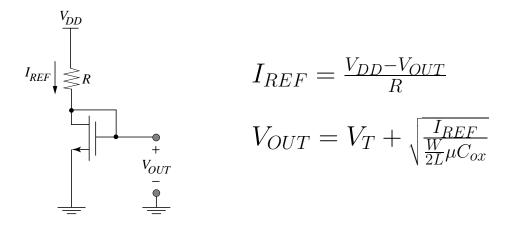
$$I_{OUT1} = I_{REF} \frac{\left(\frac{W}{L}\right)_1}{\left(\frac{W}{L}\right)_R}$$

$$I_{OUT2} = I_{REF} \frac{\left(\frac{W}{L}\right)_2}{\left(\frac{W}{L}\right)_R}$$

$$I_{OUT4} = I_{OUT1} \frac{\left(\frac{W}{L}\right)_4}{\left(\frac{W}{L}\right)_3} = I_{REF} \frac{\left(\frac{W}{L}\right)_4 \left(\frac{W}{L}\right)_1}{\left(\frac{W}{L}\right)_3 \left(\frac{W}{L}\right)_R}$$

## $\square$ Generating $I_{REF}$ :

Simple circuit:



For large W/L,

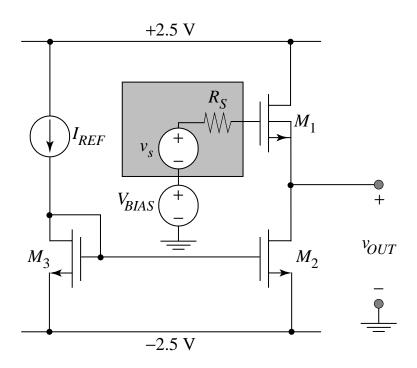
$$I_{REF} \simeq \frac{V_{DD} - V_T}{R}$$

- Advantages:
  - $-I_{REF}$  set by value of resistor.
- Disadvantages:
  - $-V_{DD}$  also affects  $I_{REF}$ .
  - $-V_T$  and R are function of temperature  $\Rightarrow I_{REF}(T)$ .

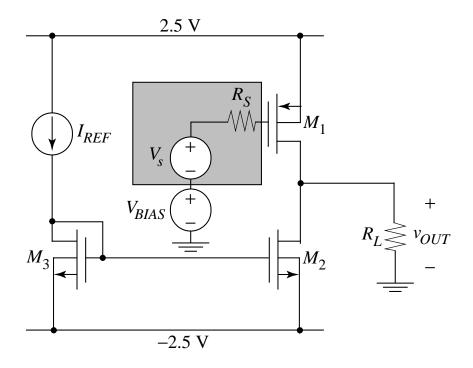
In real world, more sophisticated circuits used to generate  $I_{REF}$  that are  $V_{DD}$  and T independent.

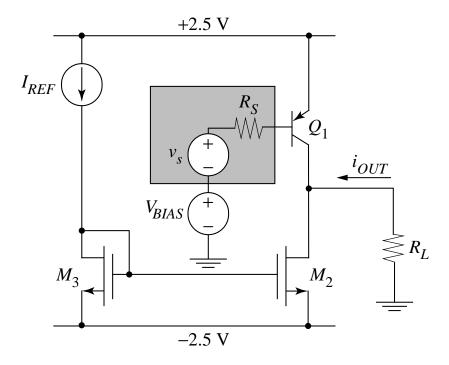
 $\square$  Can now understand more complex circuits.

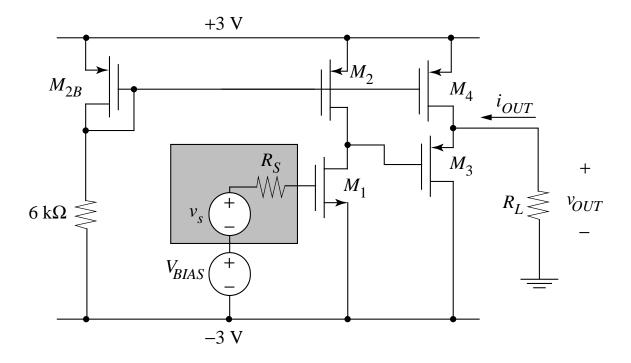
## Examples:

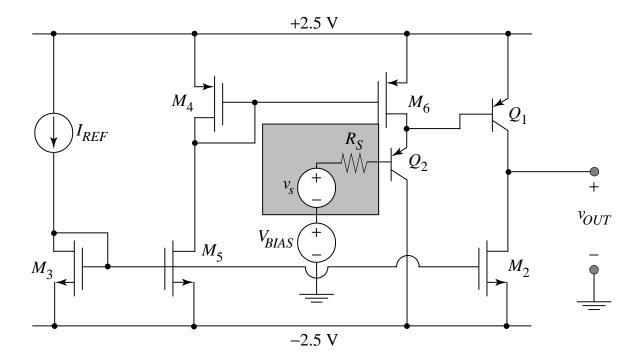


Amp stages:









## **Key conclusions**

- Voltage source easily synthesized from current source using MOSFET in diode configuration.
- Current source easily synthesized from current source using *current mirror* circuit.
- Multiple current sources and sinks with different magnitudes of current can be synthesized from a single current source.
- Voltage and current sources rely on availability of well "matched" transistors in IC technology.